

Low ON Resistance Nch Load Switch IC

NO.EA-319-190108

OUTLINE

The R5541K is a CMOS-based dual supply voltage load switch IC. The R5541K is an ideal switch for supplying the power from the secondary power source such as the output of a step-down DC/DC converter to the load circuit. A built-in Nch. transistor with typically 18 m Ω ON resistance allows the R5541K to provide a low dropout voltage and prevents the reverse current during shutdown mode. Internally, a single IC consists of an internal voltage step-up circuit, a soft-start circuit, a thermal shutdown circuit, a chip enable circuit and a UVLO circuit.

The gate voltage of Nch. driver transistor is supplied by a soft-start circuit. The soft-start circuit is supplied by the external power source (V_{BIAS}). Soft-start time is adjustable by connecting an external capacitor.

The R5541K is offered in an ultra-small 6-pin DFN(PL)1216-6G package which achieve the smallest possible footprint solution on boards where area is limited.

FEATURES

- Standby Current······ Typ. 0.01 µA
- V_{IN} Input Voltage Range 0.6 V to 4.8 V
- V_{BIAS} Input Voltage Range ······ 2.5 V to 5.5 V
- Switch ON Resistance ······Typ. 18 m Ω (V_{IN} = 1.0 V, V_{BIAS} = 5.0 V)
- Output Current Max. 3 A
- A single Nch MOSFET Circuit
- Soft-start Function
- Thermal Shutdown Circuit
- Auto-discharge Function (R5541K001D)
- Package DFN(PL)1216-6G

APPLICATIONS

Secondary Power Source for hand-held communication equipments and laptop PCs

BLOCK DIAGRAMS



SELECTION GUIDE

The auto-discharge function^{*1} is a user-selectable option.

Selection Guide

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
R5541K001*-E2	DFN(PL)1216-6G	5,000 pcs	Yes	Yes
*: Specify the CE Pin Polarity and auto-discharge option.				
D: Active-High, auto-discharge function				

^{*1} Auto-discharge function quickly lowers the output voltage to 0 V, when the chip enable signal is switched from the active mode to the standby mode, by releasing the electrical charge accumulated in the external capacitor.

PIN DESCRIPTION



DFN(PL)1216-6G Pin Description

Pin No.	Symbol	Description
1	CE	Chip Enable Pin (Active-High)
2	VIN	Input Pin 2 ^{*1}
3	VBIAS	Input Pin 1 ^{*1}
4	GND	Ground Pin
5	V _{OUT}	Output Pin
6	DELAY	DELAY Pin for Soft-start Setting

*1 V_{IN} should be used as $V_{IN} \leq V_{BIAS}$.

ABSOLUTE MAXIMUM RATINGS

Symbol	Item	Rating	Unit
VBIAS	V _{BIAS} Pin Input Voltage	-0.3 to 6.0	V
VIN	V _{IN} Pin Input Voltage	-0.3 to 5.5	V
Vce	CE Pin Input Voltage	-0.3 to 6.0	V
Vout	Vout Pin Voltage	−0.3 to V _{IN}	V
Ιουτ	Output Current	3.0	А
P _D	Power Dissipation (JEDEC STD.51-7 Test Land Pattern) ^{*1}	714	mW
Tj	Junction Temperature	-40 to 125	°C
Tstg	Storage Temperature Range	-55 to 125	°C

Absolute Maximum Ratings

^{*1} Refer to *PACKAGE INFORMATION* for detailed information.

ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause the permanent damages and may degrade the life time and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings is not assured.

RECOMMENDED OPERATING CONDITIONS (ELECTRICAL CHARACTERISTICS)

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

ELECTRICAL CHARACTERISTICS

 $V_{BIAS} = 5.0 \text{ V}, V_{IN} = 1.0 \text{ V}, C_{BIAS} = 1 \ \mu\text{F}, C_{IN} = \text{none}, C_{OUT} = 0.1 \ \mu\text{F}, \text{ unless otherwise noted}.$ The specifications surrounded by are guaranteed by Design Engineering at $-40^{\circ}\text{C} \le \text{Ta} \le 85^{\circ}\text{C}.$

R5541K Electrical Characteristics (Ta = 25°C)							
Symbol	Item	Conditions		Min.	Тур.	Max.	Unit
VBIAS	V _{BIAS} Pin Input Voltage			2.5		5.5	V
VIN	V _{IN} Pin Input Voltage			0.6		4.8	V
Ron	Switch ON Resistance	Ι _{ουτ} = 500 mA			18	28	mΩ
lss	Supply Current	I _{OUT} = 0 mA, V _{BIAS} Pin			25	47	μA
Istandby	Standby Current	V _{CE} = 0 V, V _{IN} = 4.8 V, V _{BIAS} = 5.5 V	VBIAS Pin		0.01	0.15	μA
			V _{IN} Pin		0.01	1	μA
	Undervoltage Lockout Voltage	V _{BIAS} Pin ^{*1}		2.0		2.49	V
UVLO		V _{IN} Pin ^{*2}		0.3		0.59	V
T _{TSD}	Thermal Shutdown Temperature	Junction Temperature			145		°C
T _{TSR}	Thermal Shutdown Release Temperature	Junction Temperature			125		°C
ICEPD	CE Pull-down Current				0.4	0.8	μA
Vсен	CE Input Voltage "H"			1.0			V
VCEL	CE Input Voltage "L"					0.4	V
IDELAY	DELAY Pin Current	*3		1.25	1.5	1.8	μA
RLOW	Low Output Nch Tr. ON Resistance (R5541K001D)	V _{CE} = 0 V			80		Ω

All test items listed under ELECTRICAL CHARACTERISTICS are done under the pulse load condition (Tj ≈ Ta = 25°C).

^{*1} The UVLO detector threshold and the UVLO release voltage are between the min and the max of UVLO with Typ. 90 mV hysteresis.

^{*2} The UVLO detector threshold and the UVLO release voltage are between the min and the max of UVLO with Typ. 70 mV hysteresis.

^{*3} Soft-start time can be adjusted by using I_{DELAY} and a capacitor (C_D). Refer to *Soft-start Function* in *TECHNICAL NOTES* for detailed Information.

TYPICAL APPLICATION



R5541K Typical Application

TECHNICAL NOTES

The performance of a power source circuit using this device is highly dependent on a peripheral circuit. A peripheral component or the device mounted on PCB should not exceed a rated voltage, a rated current or a rated power. When designing a peripheral circuit, please be fully aware of the following points.

- An input capacitor (C_{IN}) and a bypass capacitor (C_{BIAS}) are NOT necessarily required between the V_{IN} pin and GND. If there is a possibility that the parasitic element (inductance) of V_{IN} may generate spike noise, connect an appropriate capacitor (about 0.1 μF) between the V_{IN} pin and GND.
- V_{IN} and V_{BIAS} should always be used as $V_{IN} \leq V_{BIAS}$.
- Connect the DELAY pin to a capacitor (C_D) or leave the DELAY pin floating.

SOFT-START FUNCTION

Soft-start function maintains the smooth control of the output voltage to prevent an inrush current during startup by adjusting the soft-start time (tstart) (V_{OUT} = 10% to 90%). tstart can be adjusted by connecting a capacitor (C_D) between the DELAY pin and GND. The calculation of C_D is as follows.

 C_D [nF] = 7.5 x tstart [ms] x I_{DELAY} [µA] / V_{IN} [V]

If C_D is not connected to the DELAY pin, leave the DELAY pin floating. If the DELAY pin is left floating, the calculation of the start-up time (tr) (V_{OUT} = 10% to 90%) is as follows.

tr [ms] = 0.04 x V_{IN} [V] (Typ.)

 V_{BIAS} , V_{IN} and CE can be sequenced in any order; the device can start up with soft-start function.

PACKAGE INFORMATION

POWER DISSIPATION (DFN(PL)1216-6G)

Power Dissipation (P_D) of the package is dependent on PCB material, layout, and environmental conditions. The following conditions are used in this measurement.

	JEDEC STD.51-7 Test Land Pattern		
Environment	Mounting on Board (Wind Velocity = 0m/s)		
Board Material	Glass Cloth Epoxy Plastic (4 Layer)		
Board Dimensions	76.2 mm × 114.3 mm × 1.6 mm		
Copper Ratio	Top side, Back side: 60 mm x 60mm, Approx.10% 2nd, 3rd layers: 74.2 mm x 74.2 mm, Approx. 100%		
Through-holes	φ 0.85 mm x 44 pcs		

Measurement Conditions

Measurement Result $(Ta = 25^{\circ}C, Tjmax = 125^{\circ}C)$ JEDEC STD.51-7 Test Land PatternPower Dissipation714 mWThermal
Resistance $\theta ja = (125 - 25^{\circ}C) / 0.714 W = 140^{\circ}C/W$ $\theta jc = 21^{\circ}C/W$







NO.EA-319-190108

PACKAGE DIMENSIONS (DFN(PL)1216-6G)



DFN(PL)1216-6G Package Dimensions

MARK SPECIFICATION (DFN(PL)1216-6G)

①②③④: Product Code ... Refer to MARK SPECIFICATION TABLE DFN(PL)1216-6G.

⑤ ⑥: Lot Number ... Alphanumeric Serial Number



DFN(PL)1216-6G Mark Specification

MARK SPECIFICATION TABLE (DFN(PL)1216-6G)

Mark Specification Table

Product Name	0234
R5541K001B	D Z 0 1
R5541K001D	D Z 0 3

NO.EA-319-190108

TYPICAL CHARACTERISTICS

Note: Typical Characteristics are intended to be used as reference data; they are not guaranteed.



Switch On Resistance vs. VBIAS Input Voltage

R5541K001x VBIAS = 5.0 V, IOUT = 500 mA, Ta = 25°C



Switch On Resistance vs. VIN Input Voltage



R5541K001x

Switch On Resistance vs. VBIAS Input Voltage

R5541K001x V_{IN} = 1.0 V, V_{BIAS} = 5.0 V, I_{OUT} = 500 mA



Switch On Resistance vs. Temperature

NO.EA-319-190108



 $V_{\ensuremath{\mathbb N}\xspace}$ Supply Current vs. $V_{\ensuremath{\mathbb N}\xspace}$ Input Voltage

R5541K001x V_{BIAS} = 5.5 V



V_{IN} Supply Current vs. Temperature



VBIAS Supply Current vs. VBIAS Input Voltage

R5541K001x V_{IN} = 0.6 V



VBIAS Supply Current vs. Temperature

NO.EA-319-190108





R5541K001x V_{BIAS} = 5.5 V



V_{IN} Standby Current vs. Temperature



VIN Standby Current vs. VBIAS Input Voltage

R5541K001x V_{IN} = 0.6 V



VBIAS Standby Current vs. Temperature



VOUT Output Voltage On Time vs. DELAY Capacitance





Vout Output Voltage On Time vs. V_{IN} Input Voltage



VOUT Output Voltage On Time vs. Load Resistance



R5541K001D V_{BIAS} = 5.0 V, C_D = 10 nF, C_{OUT} = 0.1 μF



 V_{OUT} Output Voltage Off Time vs. V_{IN} Input Voltage

 $\label{eq:KS541K001D} R5541K001D \\ V_{\text{IN}} = 4.8 \text{ V}, \text{ } V_{\text{BIAS}} = 5.0 \text{ } \text{V}, \text{ } \text{C}_{\text{D}} = 10 \text{ } \text{nF}, \text{ } \text{C}_{\text{OUT}} = 0.1 \text{ } \mu\text{F}$



VOUT Output Voltage Off Time vs. Load Resistance





 $\label{eq:result} \begin{array}{l} R5541K001x\\ V_{\text{IN}} = 1.0 \text{ V}, \text{ C}_{\text{D}} = 10 \text{ nF}, \text{ } \text{R}_{\text{LOAD}} = 10 \text{ } \Omega, \text{ } \text{C}_{\text{OUT}} = 0.1 \text{ } \mu\text{F} \end{array}$



tr vs. V_{BIAS} Input Voltage

 $\label{eq:Kinetic} \begin{array}{l} R5541K001x\\ V_{\text{IN}} = 1.0 \ V, \ R_{\text{LOAD}} = 10 \ \Omega, \ C_{\text{OUT}} = 0.1 \ \mu\text{F} \end{array}$



VOUT Output Voltage On Time vs. VBIAS Input Voltage



VOUT Output Voltage Off Time vs. Load Resistance

R5541K001x V_{IN} = 1.0 V, C_D = 10 nF, R_{LOAD} = 10 Ω, C_{OUT} = 0.1 μ F



ton Turn-on Time vs. VBIAS Input Voltage

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